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# HMC695\* Product Page Quick Links

Last Content Update: 08/30/2016

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## [Comparable Parts](#)

View a parametric search of comparable parts

## [Evaluation Kits](#)

- HMC695LP4 Evaluation Board

## [Documentation](#)

### **Data Sheet**

- HMC695 Data Sheet

## [Tools and Simulations](#)

- HMC695 S-Parameter

## [Reference Materials](#)

### **Quality Documentation**

- Package/Assembly Qualification Test Report: LP4, LP4B, LP4C, LP4K (QTR: 2013-00487 REV: 04)
- Semiconductor Qualification Test Report: GaAs HBT-A (QTR: 2013-00228)

## [Design Resources](#)

- HMC695 Material Declaration
- PCN-PDN Information
- Quality And Reliability
- Symbols and Footprints

## [Discussions](#)

View all HMC695 EngineerZone Discussions

## [Sample and Buy](#)

Visit the product page to see pricing options

## [Technical Support](#)

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## SMT GaAs HBT MMIC x4 ACTIVE FREQUENCY MULTIPLIER 11.4 - 13.2 GHz OUTPUT

### Typical Applications

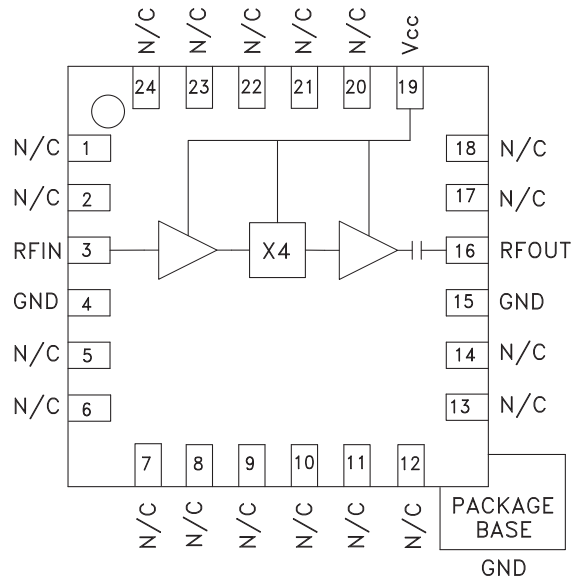
The HMC695LP4(E) is ideal for:

- Fiber Optic Applications
- Point-to-Point Radios
- Military Radar

### Features

- Output Power: +7 dBm
- Sub-Harmonic Suppression: >25 dBc
- SSB Phase Noise: -140 dBc/Hz
- Single Supply: +5V @ 60 mA
- 24 Lead 4x4 mm SMT Package: 16 mm<sup>2</sup>

### Functional Diagram

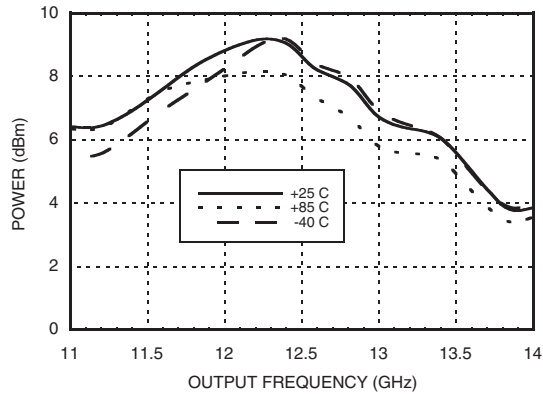
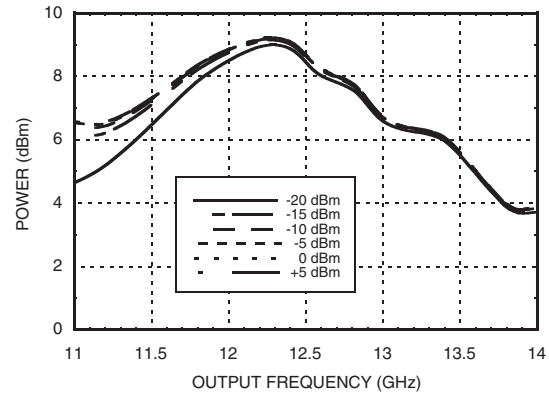
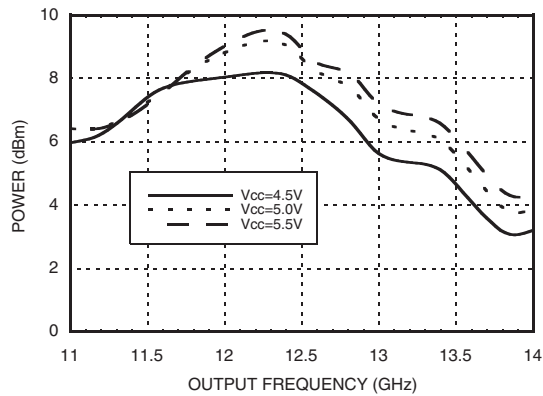
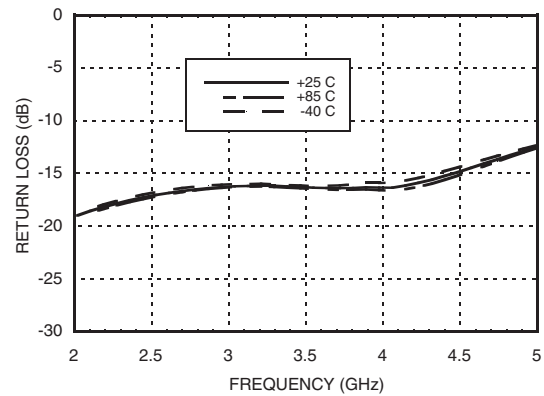
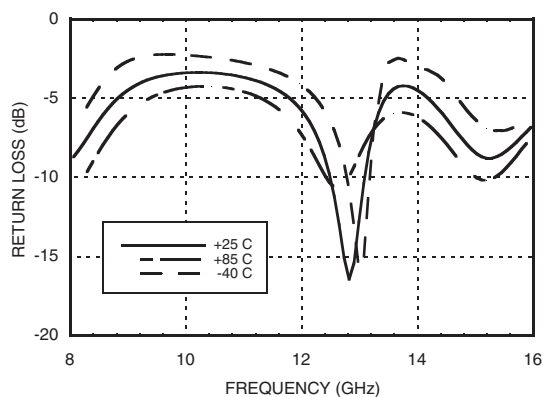
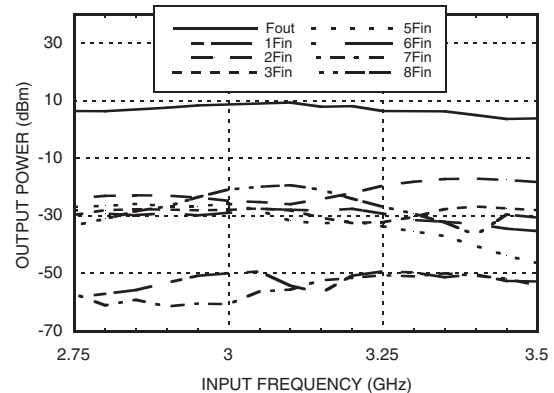


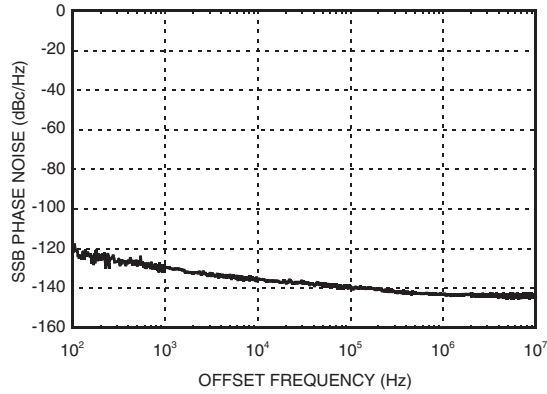
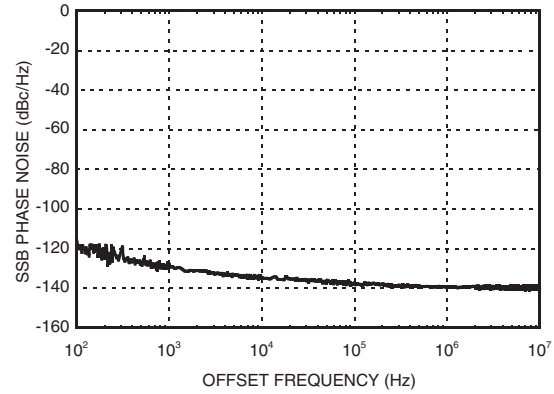
### General Description

The HMC695LP4(E) are active miniature x4 frequency multipliers utilizing InGaP GaAs HBT technology in 4x4 mm leadless surface mount packages. Power output is +7 dBm typical from a +5V supply voltage and varies little vs. input power, temperature and supply voltage. Suppression of undesired fundamental and sub-harmonics is >25 dBc typical with respect to output signal level. The low additive SSB phase noise of -140 dBc/Hz at 100 kHz offset helps the user maintain good system noise performance. The HMC695LP4(E) are ideal for use in LO multiplier chains allowing reduced parts count vs. traditional approaches.

### Electrical Specifications, $T_A = +25^\circ \text{C}$ , $V_{CC} = 5V$

Parameter	Min.	Typ.	Max.	Units
Frequency Range, Input	2.85 - 3.3			GHz
Frequency Range, Output	11.4 - 13.2			GHz
Input Power Range	-15		5	dBm
Output Power	2	7		dBm
Sub-Harmonic Suppression		25		dBc
Input Return Loss		15		dB
Output Return Loss		8		dB
SSB Phase Noise (100 kHz Offset)	Pin= 0 dBm	-140		dBc/Hz
Supply Current (I <sub>cc</sub> )		60	75	mA

**Output Power vs. Temperature @ -10 dBm Drive Level**

**Output Power vs. Drive Level**

**Output Power vs. Supply Voltage @ -10 dBm Drive Level**

**Input Return Loss vs. Temperature**

**Output Return Loss vs. Temperature**

**Harmonics @ -10 dBm Drive Level**



**SMT GaAs HBT MMIC x4 ACTIVE FREQUENCY MULTIPLIER  
11.4 - 13.2 GHz OUTPUT**
**SSB Phase Noise**
**@ Pin = 0 dBm @ 12.5 GHz**

**SSB Phase Noise**
**@ Pin = -10 dBm @ 12.5 GHz**

**Absolute Maximum Ratings**

RF Input (Vcc= +5V)	+20 dBm
Vcc	+5.5V
Channel Temperature	135 °C
Continuous P <sub>diss</sub> (T=85 °C) (derate 10.8 mW/°C above 85 °C)	538 mW
Thermal Resistance (R <sub>thj</sub> ) (junction to ground paddle)	93 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 1B

**Typical Supply Current vs. Vcc**

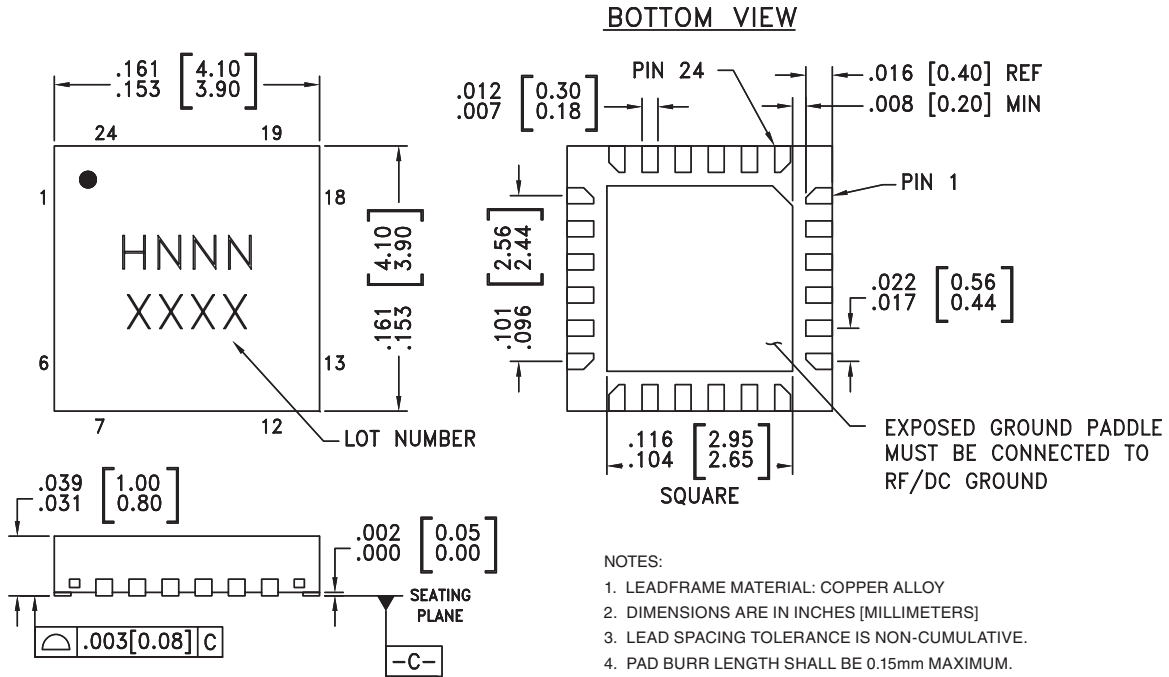
Vcc (V)	I <sub>cc</sub> (mA)
4.75	59
5.00	60
5.25	61

Note: Multiplier will operate over full voltage range shown above.



**ELECTROSTATIC SENSITIVE DEVICE  
OBSERVE HANDLING PRECAUTIONS**

### Outline Drawing



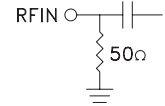

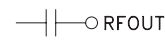
- NOTES:
1. LEADFRAME MATERIAL: COPPER ALLOY
  2. DIMENSIONS ARE IN INCHES [MILLIMETERS]
  3. LEAD SPACING TOLERANCE IS NON-CUMULATIVE.
  4. PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM.  
PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM.
  5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
  6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
  7. REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED LAND PATTERN.

### Package Information

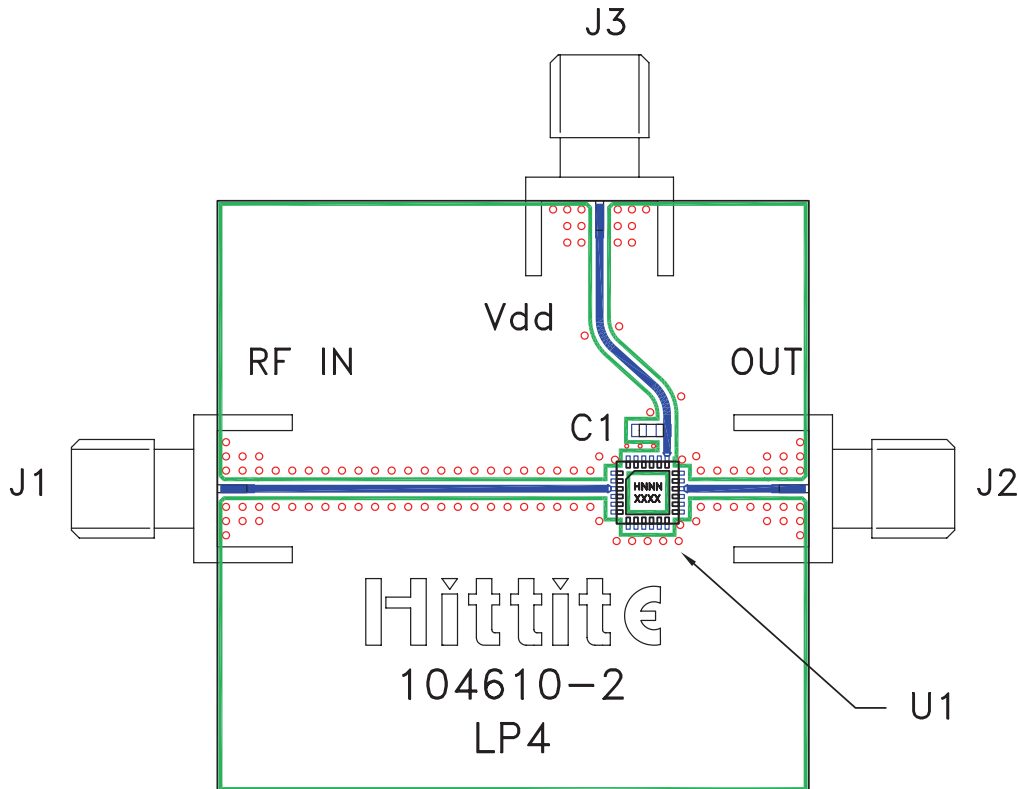
Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking <sup>[3]</sup>
HMC695LP4	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 <sup>[1]</sup>	H695 XXXX
HMC695LP4E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 <sup>[2]</sup>	H695 XXXX

[1] Max peak reflow temperature of 235 °C  
 [2] Max peak reflow temperature of 260 °C  
 [3] 4-Digit lot number XXXX


**SMT GaAs HBT MMIC x4 ACTIVE FREQUENCY MULTIPLIER  
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**Pin Description**

Pin Number	Function	Description	Interface Schematic
1, 2, 5 - 14, 17, 18, 20 - 24	N/C	The pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/DC ground externally.	
3	RFIN	RF input needs to be DC blocked only if there is an external DC voltage applied to RFIN.	
4, 15	GND	All ground leads and ground paddle must be soldered to PCB RF/DC ground.	
16	RFOUT	Multiplied Output. AC coupled. No external DC blocks necessary.	
19	Vcc	Supply voltage 5V	



**Evaluation PCB**

**List of Materials for Evaluation PCB 106137 [1]**

Item	Description
J1 - J3	PCB Mount SMA Connector
C1	1,000 pF Capacitor, 0603 Pkg.
U1	HMC695LP4(E) x4 Active Multiplier
PCB [2]	104610 Eval Board

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Arlon 25FR or Rogers 4350

The circuit board used in the application should be generated with proper RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. The evaluation circuit board shown is available from Hittite upon request.